



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL31B226MPHNNNE

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 22 µF, 10V, ±20%, X7R, 1206

A. Samsung Part Number

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① Se	eries	Samsung Multi-layer Ceramic Capacitor									
② Si	ize	1206	(inch c	ode)	L:	3.2	± 0.2	mm	W:	1.6 ± 0.2	mm
③ Di	ielectric	X7R				8	Inner el	lectrode	N	li	
4 Ca	apacitance	22	μF				Termin	ation	C	Cu	
⑤ Ca	apacitance	±20	%				Plating		S	n 100%	(Pb Free)
to	olerance					9	Produc	t	N	Iormal	
6 Ra	ated Voltage	10	V			10	Special		F	Reserved for	future use
7 Th	hickness	1.6	± 0.2	mm		11)	Packag	ing	Е	mbossed T	ype, 7" reel

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition					
Capacitance	Within specified tolerance	120Hz±20% 0.5±0.1Vrms					
Tan δ (DF)	0.1 max.						
Insulation	10,000Mohm or 100Mohm⋅μF	Rated Voltage 60~120 sec.					
Resistance	Whichever is Smaller						
Appearance	No abnormal exterior appearance	Microscope (×10)					
Withstanding	No dielectric breakdown or	250% of the rated voltage					
Voltage	mechanical breakdown						
Temperature	X7R						
Characteristics	(From -55℃ to 125℃, Capacitance change should be within ±15%)						
Adhesive Strength	No peeling shall occur on the	500g·F, for 10±1 sec.					
of Termination	terminal electrode						
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)					
		with 1.0mm/sec.					
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder					
	is to be soldered newly	245±5℃, 3±0.3sec.					
		(preheating : 80~120 ℃ for 10~30sec.)					
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.					
Soldering heat	Tan δ, IR : initial spec.						

	Performance	Test condition				
Vibration Test	Capacitance change: within ±5%	Amplitude : 1.5mm				
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)				
		2hours × 3 direction (x, y, z)				
Moisture	Capacitance change: within ±12.5%	With rated voltage				
Resistance	Tan δ : 0.125 max	40±2℃, 90~95%RH, 500+12/-0hrs				
	IR: 12.5MΩ·μF or Over					
High Temperature	Capacitance change: within ±12.5%	With 150% of the rated voltage				
Resistance	Tan δ: 0.125 max	Max. operating temperature				
	IR: 25MΩ·μF or Over					
		1000+48/-0hrs				
Temperature	Capacitance change: within ±7.5%	1 cycle condition				
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25 °C				
		$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}$ C				
		5 cycle test				

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C, 10sec. Max)

^{*} For more detailed Specification, Please refer to the Samsung MLCC catalogue.